## Tune Report

Operator Name ICPMS QQQ 8900

Acq/Data Batch D:\Agilent\ICPMH\1\DATA\2024\121224(1).b

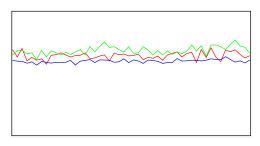
**Acq. Date-Time** 12/12/2024 12:01:42 PM

Report Comment ---

Instrument Name G3665A SG23363340

## [He]

## Sensitivity



Mass	Range	Count	RSD%	Background
59	1000	645	4.597	
89	1000	687	4.840	
205	5000	2999	2.211	

Sampling Period [sec] 0.31 Integration Time [sec] 0.1

#### Oxide/Doubly Charged Ratio

Oxide 156 / 140 0.138 % Doubly Charged 70 / 140 0.809 %

#### **Tune Parameters**

#### Plasma Parameters

Q2 Mass Gain

125

Plasma Mode		Nebulizer Gas	0.75 L/min	Dilution Gas	0.40 L/min					
RF Power	1600 W	Option Gas	0.0 %	Auxiliary Gas	0.90 L/min					
RF Matching	1.60 V	Nebulizer Pump	0.10 rps	Plasma Gas	15.0 L/min					
Sample Depth	10.0 mm	S/C Temp	2 °C							
Lens Parameters										
Extract 1	0.0 V	Q1 Entrance	-50.0 V	Cell Exit	-60 V					
Extract 2	-175.0 V	Q1 Exit	2.0 V	Deflect	-4.2 V					
Omega Bias	-85 V	Cell Focus	-4.0 V	Plate Bias	-60 V					
Omega Lens	8.0 V	Cell Entrance	-50 V							
Q1 Parameters										
Q1 Mass Gain	126	Q1 Bias	-5.0 V							
Q1 Mass Offset	127	Q1 Prefilter Bias	-9.5 V							
Q1 Axis Gain	0.9999	Q1 Postfilter Bias	-6.0 V							
Q1 Axis Offset	-0.06									
Q1 Ion Guide Parameters										
SLS Factor	0.60	SLG Factor	0.90							
Cell Parameters										
Use Gas	Yes	3rd Gas Flow	0 %	Axial Acceleration	1.0 V					
He Flow	5.0 mL/min	4th Gas Flow	0 %	OctP RF	170 V					
H2 Flow		OctP Bias	-18.0 V	Energy Discrimination	n 3.0 V					
Q2 Parameters										

0.9995

Q2 Axis Gain

-15.0 V

Q2 Bias

# Tune Report

Q2 Mass Offset 126 Q2 Axis Offset 0.04

Q2 Ion Guide Parameters

SLS Factor 0.50 SLG Factor 1.00

Wait Time Offset

Wait Time Offset 0 msec

**Hardware Settings** 

Torch

 Torch H
 0.3 mm
 Torch V
 0.1 mm

EΜ

Discriminator 2.7 mV Analog HV 2188 V Pulse HV 1169 V